

## ABSTRACT OF THE DISCLOSURE

Disclosed herein is a wavelength converted light emitting apparatus comprising a substrate, a light emitting diode, and a phosphor layer. The substrate is formed at its upper surface with first and second conductive patterns. At a partial region of the first conductive pattern and at the second conductive pattern are formed first and second connection bumps, respectively. The light emitting diode has first and second surfaces opposite to each other, and a side surface. The first surface of the light emitting diode is formed with first and second electrodes. The light emitting diode is disposed at the upper surface of the substrate so that the first and second electrodes are connected to the first and second connection bumps, respectively. The phosphor layer is formed along the second surface and side surface of the light emitting diode by a certain thickness, thereby serving to convert a wavelength of light emitted from the light emitting diode.